

KHX4200S2LL/2G

2GB 256M x 64-Bit PC2-4200

CL3 200-Pin SODIMM



DESCRIPTION

This document describes ValueRAM's 256M x 64-bit 2GB (2048MB) PC2-4200 CL3 SDRAM (Synchronous DRAM) memory module. The module is based on sixteen 128M x 8-bit DDR2 FBGA components. The SPDs are programmed to JEDEC low latency timing of 3-3-3-8 at 1.8V. This 200-pin SODIMM uses gold contact fingers and requires +1.8V. The electrical and mechanical specifications are as follows:

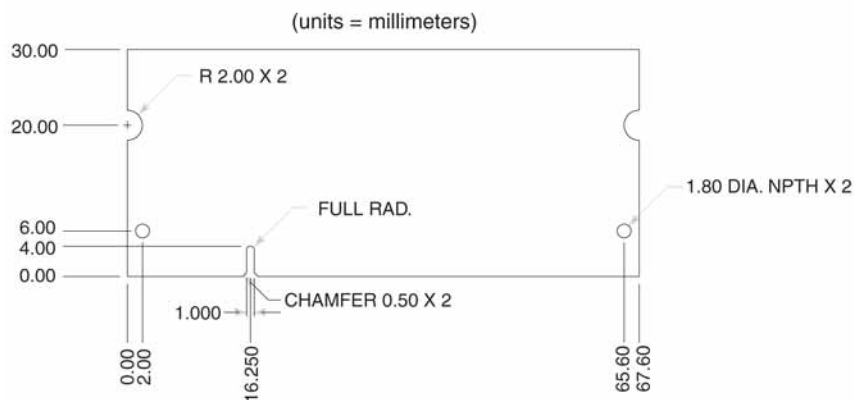
SPECIFICATIONS

Clock Cycle Time (tCK) CL=3	3.7ns (min.) / 8ns (max.)
Row Cycle Time (tRC)	55ns (min.)
Refresh to Active/Refresh Command Time (tRFC)	127.5ns
Row Active Time (tRAS)	40ns (min.) / 70,000ns (max.)
Single Power Supply of	+1.8V (+/- .1V)
Power	1.396 W (operating per module)
UL Rating	94 V - 0
Operating Temperature	0° C to 55° C
Storage Temperature	-55° C to +125° C

FEATURES

- Power supply : Vdd: 1.8V \pm 0.1V, Vddq: 1.8V \pm 0.1V
- Double-data-rate architecture; two data transfers per clock cycle
- Bidirectional data strobe(DQS)
- Differential clock inputs(CK and CK)
- DLL aligns DQ and DQS transition with CK transition
- Programmable Read latency 5, 4, 3 (clock)
- Burst Length: 4, 8 (Interleave/nibble sequential)
- Programmable Burst type (sequential & interleave)
- Timing Reference: 3-3-3-8 at +1.8V
- Edge aligned data output, center aligned data input
- Auto & Self refresh, 7.8us refresh interval (8K/64ms refresh)
- Serial presence detect with EEPROM
- PCB : Height 1.180" (30.00mm), double sided component

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All Kingston products are tested to meet our published specifications. Some motherboards or system configurations may not operate at the published HyperX memory speeds and timing settings. Kingston does not recommend that any user attempt to run their computers faster than the published speed. Overclocking or modifying your system timing may result in damage to computer components.